Integrated Device Technology, Inc.

3.3V CMOS SINGLE 2-INPUT POSITIVE-OR GATE

IDT74ALVC1G32
ADVANCE INFORMATION

FEATURES:

- 0.5 MICRON CMOS Technology
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- 0.65mm pitch PSOP package
- Extended commercial range of – 40°C to + 85°C
- V_{CC} = 3.3V ± 0.3V, Normal Range
- V_{CC} = 1.65V to 3.6V, Extended Range
- V_{CC} = 2.5V ± 0.2V
- CMOS power levels (0.4µW typ. static)
- Rail-to-Rail output swing for increased noise margin

Drive Features for ALVC1G32:

- High Output Drivers: ±24mA
- Suitable for heavy loads

DESCRIPTION:

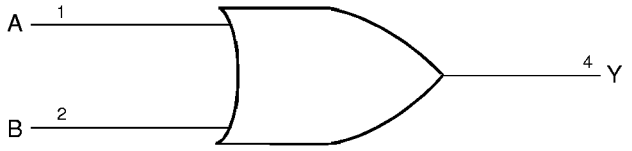
This single 2-input positive-OR gate is built using advanced dual metal CMOS technology. The ALVC1G32 is designed for 1.65V to 3.6V V_{CC} operation and performs the Boolean function $Y = A + B$ or $Y = \overline{\overline{A} \cdot \overline{B}}$ in positive logic.

The ALVC1G32 has been designed with a ±24mA output driver. This driver is capable of driving a moderate to heavy load while maintaining speed performance.

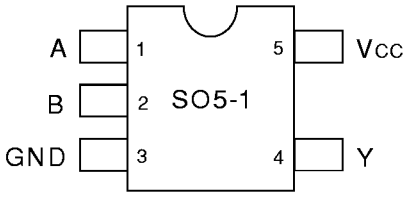
APPLICATIONS:

- 3.3V High Speed Systems
- 3.3V and lower voltage computing systems

FUNCTIONAL BLOCK DIAGRAM



PIN CONFIGURATION



PSOP
TOP VIEW

PIN DESCRIPTION

Pin Names	Description
A, B	Data Inputs
Y	Data Output

FUNCTION TABLE[1]

Inputs		Output
A	**B**	**Y**
H	X	H
X	H	H
L	L	L

NOTE:
1. H = HIGH Voltage Level
   L = LOW Voltage Level
   X = Don't Care

DSC-4532/-

ABSOLUTE MAXIMUM RATING(1)

Symbol	Description	Max.	Unit
V_{TERM}(2)	Terminal Voltage with Respect to GND	– 0.5 to + 4.6	V
V_{TERM}(3)	Terminal Voltage with Respect to GND	–0.5 to V_{CC} + 0.5	V
T_{STG}	Storage Temperature	– 65 to + 150	°C
I_{OUT}	DC Output Current	– 50 to + 50	mA
I_{IK}	Continuous Clamp Current, V_I < 0 or V_I > V_{CC}	± 50	mA
I_{OK}	Continuous Clamp Current, V_O < 0	– 50	mA
I_{CC} I_{SS}	Continuous Current through each V_{CC} or GND	±100	mA

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NOTES:
1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
2. V_{CC} terminals.
3. All terminals except V_{CC}.

CAPACITANCE (T_A = +25°C, f = 1.0MHz)

Symbol	Parameter(1)	Conditions	Typ.	Max.	Unit
C_{IN}	Input Capacitance	V_{IN} = 0V	5	7	pF
C_{OUT}	Output Capacitance	V_{OUT} = 0V	7	9	pF
$C_{I/O}$	I/O Port Capacitance	V_{IN} = 0V	7	9	pF

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NOTE:
1. As applicable to the device type.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:
Operating Condition: T_A = – 40°C to +85°C, V_{CC} = 2.3V to 3.6V

Symbol	Parameter	Test Conditions		Min.	Typ.(1)	Max.	Unit
V_{IH}	Input HIGH Voltage Level	V_{CC} = 1.65V to 1.95V		0.65 x V_{CC}	—	—	V
		V_{CC} = 2.3V to 2.7V		1.7	—	—	
		V_{CC} = 2.7V to 3.6V		2	—	—	
V_{IL}	Input LOW Voltage Level	V_{CC} = 1.65V to 1.95V		—	—	0.35 x V_{CC}	V
		V_{CC} = 2.3V to 2.7V		—	—	0.7	
		V_{CC} = 2.7V to 3.6V		—	—	0.8	
I_{IH}	Input HIGH Current	V_{CC} = 3.6V	V_I = V_{CC}	—	—	± 5	µA
I_{IL}	Input LOW Current	V_{CC} = 3.6V	V_I = GND	—	—	± 5	
I_{OZH}	High Impedance Output Current	V_{CC} = 3.6V	V_O = V_{CC}	—	—	± 10	µA
I_{OZL}	(3-State Output pins)		V_O = GND	—	—	± 10	µA
V_{IK}	Clamp Diode Voltage	V_{CC} = 2.3V, I_{IN} = – 18mA		—	– 0.7	– 1.2	V
V_H	Input Hysteresis	V_{CC} = 3.3V		—	100	—	mV
I_{CCL} I_{CCH} I_{CCZ}	Quiescent Power Supply Current	V_{CC} = 3.6V V_{IN} = GND or V_{CC}		—	0.1	10	µA
ΔI_{CC}	Quiescent Power Supply Current Variation	One input at V_{CC} – 0.6V, other inputs at V_{CC} or GND		—	—	750	µA

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NOTE:
1. Typical values are at V_{CC} = 3.3V, +25°C ambient.

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions[1]		Min.	Max.	Unit
V_{OH}	Output HIGH Voltage	V_{CC} = 1.65V to 3.6V	I_{OH} = – 0.1mA	V_{CC} – 0.2	—	V
		V_{CC} = 1.65V	I_{OH} = – 4mA	1.2		
		V_{CC} = 2.3V	I_{OH} = – 6mA	2	—	
		V_{CC} = 2.3V	I_{OH} = – 12mA	1.7	—	
		V_{CC} = 2.7V		2.2	—	
		V_{CC} = 3.0V		2.4	—	
		V_{CC} = 3.0V	I_{OH} = – 24mA	2	—	
V_{OL}	Output LOW Voltage	V_{CC} = 1.65V to 3.6V	I_{OL} = 0.1mA	—	0.2	V
		V_{CC} = 1.65V	I_{OL} = 4mA		0.45	
		V_{CC} = 2.3V	I_{OL} = 6mA	—	0.4	
			I_{OL} = 12mA	—	0.7	
		V_{CC} = 2.7V	I_{OL} = 12mA	—	0.4	
		V_{CC} = 3.0V	I_{OL} = 24mA	—	0.55	

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NOTE:

1. V_{IH} and V_{IL} must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate V_{CC} range. T_A = – 40°C to + 85°C.

OPERATING CHARACTERISTICS, T_A= 25°C

Symbol	Parameter	Test Conditions	V_{CC} = 1.8V ± 0.15V Typical	V_{CC} = 2.5V ± 0.2V Typical	V_{CC} = 3.3V ± 0.3V Typical	Unit
C_{PD}	Power Dissipation Capacitance	C_L = 0pF, f = 10Mhz		6	7	pF

SWITCHING CHARACTERISTICS[1]

Symbol	Parameter	V_{CC} = 1.8V ± 0.15V		V_{CC} = 2.5V ± 0.2V		V_{CC} = 2.7V		V_{CC} = 3.3V ± 0.3V		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
t_{PLH}	Propagation Delay	1	7	1	3.1		2.9	1	2.8	ns
t_{PHL}	A or B to Y									

NOTE:

1. See test circuits and waveforms. T_A = – 40°C to + 85°C.

TEST CIRCUITS AND WAVEFORMS:

TEST CONDITIONS

Symbol	$V_{CC}^{(1)}$ = 3.3V ±0.3V	$V_{CC}^{(1)}$ = 2.7V	$V_{CC}^{(2)}$ = 2.5V ±0.2V	Unit
V_{LOAD}	6	6	2 x Vcc	V
V_{IH}	2.7	2.7	Vcc	V
V_T	1.5	1.5	Vcc / 2	V
V_{LZ}	300	300	150	mV
V_{HZ}	300	300	150	mV
C_L	50	50	30	pF

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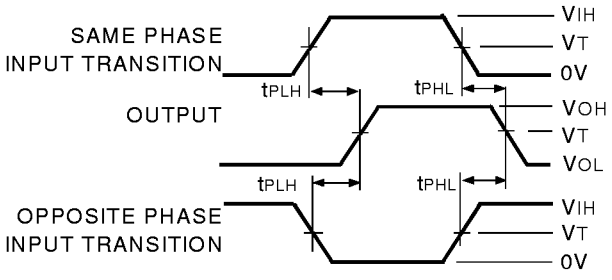
PROPAGATION DELAY



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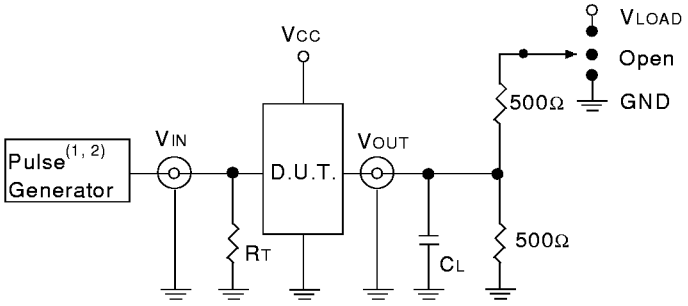
TEST CIRCUITS FOR ALL OUTPUTS



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DEFINITIONS:

C_L = Load capacitance: includes jig and probe capacitance.
R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

NOTES:

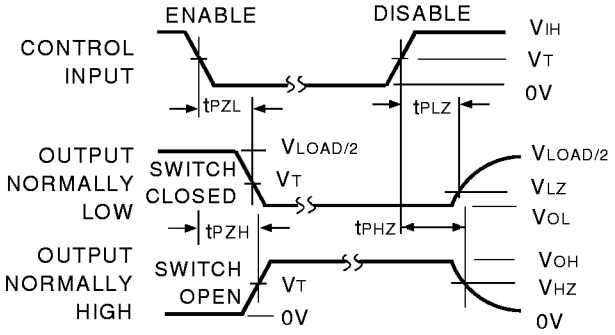
1. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_F ≤ 2.5ns; t_R ≤ 2.5ns.
2. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_F ≤ 2ns; t_R ≤ 2ns.

SWITCH POSITION:

Test	Switch
Open Drain Disable Low Enable Low	V_{LOAD}
Disable High Enable High	GND
All Other tests	Open

ALVC 1G Link

ENABLE AND DISABLE TIMES

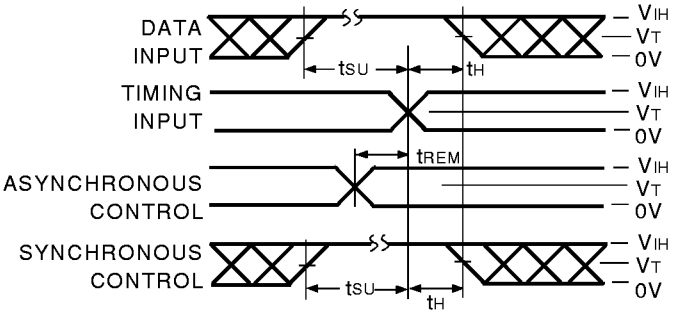


ALVC 1G Link

NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

SET-UP, HOLD AND RELEASE TIMES



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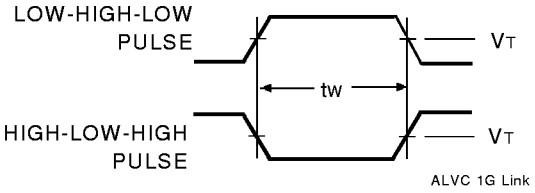
PULSE WIDTH



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1.8V ± 0.15V TEST CIRCUITS AND WAVEFORMS:

TEST CONDITIONS

Symbol	$V_{CC}^{(1)}$ = 1.8V ± 0.15V	Unit
V_{LOAD}	2 x V_{CC}	V
V_{IH}	V_{CC}	V
V_T	V_{CC} / 2	V
V_{LZ}	150	mV
V_{HZ}	150	mV
C_L	30	pF

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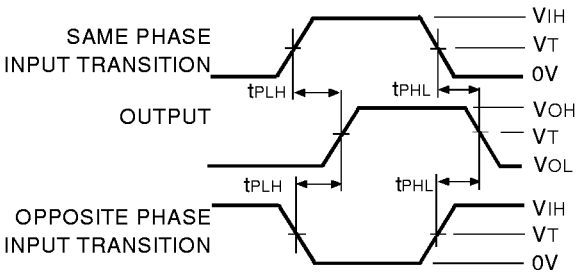
PROPAGATION DELAY



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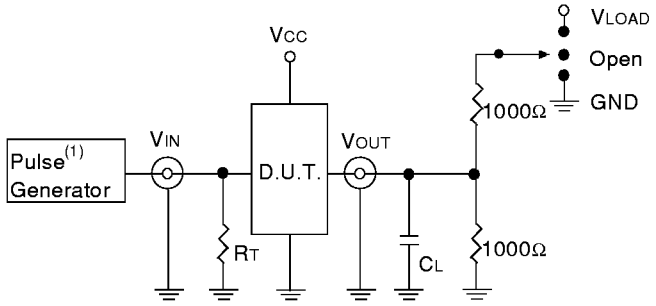
TEST CIRCUITS FOR ALL OUTPUTS



ALVC 1G Link

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R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

NOTE:

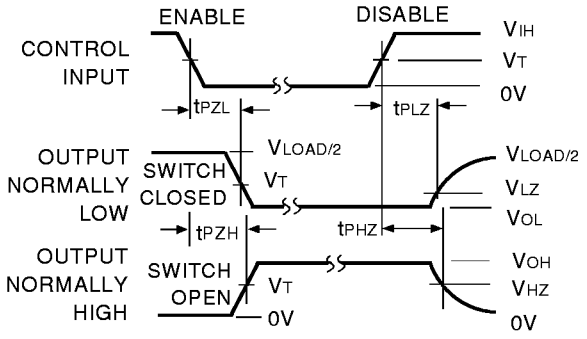
1. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_F ≤ 2ns; t_R ≤ 2ns.

SWITCH POSITION:

Test	Switch
Open Drain Disable Low Enable Low	V_{LOAD}
Disable High Enable High	GND
All Other tests	Open

ALVC 1G Link

SET-UP, HOLD AND RELEASE TIMES

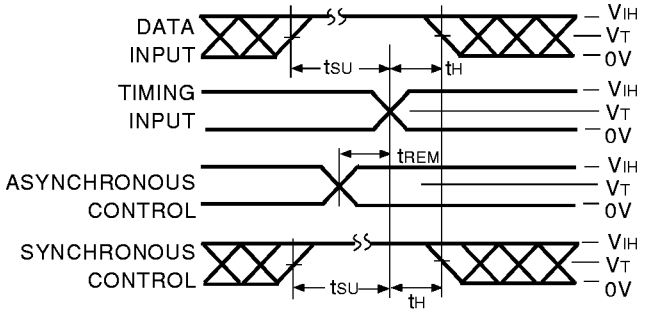


ALVC 1G Link

NOTE:

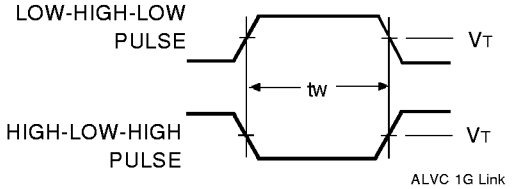
1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

ENABLE AND DISABLE TIMES



ALVC 1G Link

PULSE WIDTH



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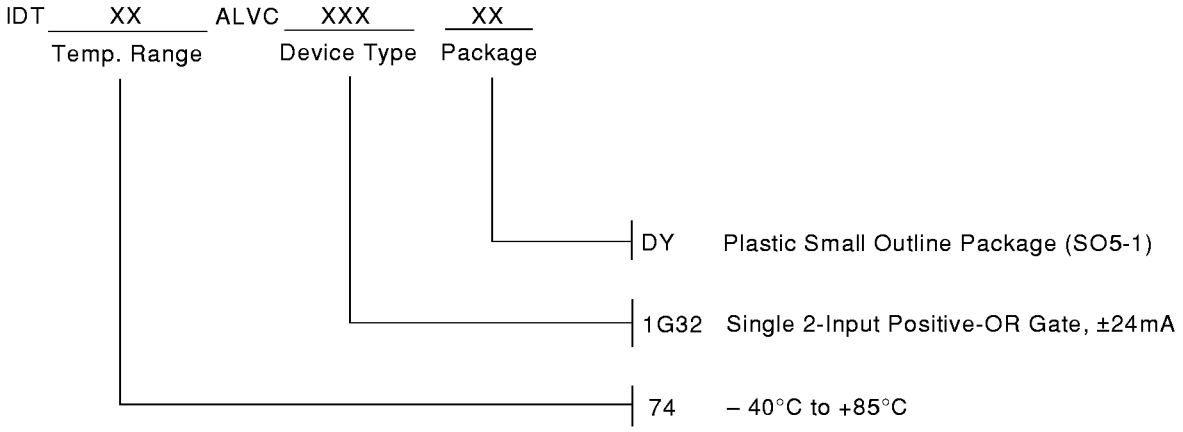
ORDERING INFORMATION



PICOGATE-LOGIC (DY) PACKAGES

Due to their small size, PicoGate-Logic packages require more complex symbolization guidelines. IDT's 5-pin PSOP (DY) packaged devices utilize a three-symbol name rule. The first symbol denotes device technology, the second symbol denotes device function, and the third symbol denotes a wafer fab/assembly site code for internal tracking.

EXAMPLES:

1. A PicoGate-Logic device with package code LR* is an IDT74LVC1G79A.
2. A PicoGate-Logic device with package code GC* is an IDT74ALVC1G04.

PICOGATE-LOGIC (DY) PACKAGE SYMBOLIZATION GUIDELINES

TECHNOLOGY	CODE
ALVC	G
ALVCH	J
LVC	L
LVCH(1)	

FUNCTION	CODE
00	A
02	B
04	C
U04	D
06(1)	
07(1)	
08	E
14	F
32	G
79	R
86	H
125	M
126	N
132(1)	

NOTE:
1. Code to be determined.